FDT434P

April 2011

FAIRCHILD

FDT434P

P-Channel 2.5V Specified PowerTrench[®] MOSFET

General Description

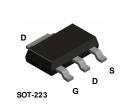
This P-Channel 2.5V specified MOSFET is produced using Fairchild Semiconductor's advanced PowerTrench process that has been especially tailored to minimize the on-state resistance and yet maintain low gate charge for superior switching performance.

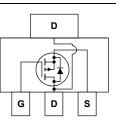
Applications

- Low Dropout Regulator
- DC/DC converter
- Load switch
- Motor driving

Features

- -5.5 A, -20 V. $R_{DS(ON)}$ = 0.050 Ω @ V_{GS} = -4.5 V $R_{DS(ON)}$ = 0.070 Ω @ V_{GS} = -2.5 V.
- Low gate charge (13nC typical)
- High performance trench technology for extremely low $R_{\text{DS}(\text{ON})}$.
- High power and current handling capability in a widely used surface mount package.





Absolute Maximum Ratings T_A=25°C unless otherwise noted

Symbol	Parameter		Ratings	Units
V _{DSS}	Drain-Source Voltage		-20	V
V _{GSS}	Gate-Source Voltage		±8	V
ID	Drain Current – Continuous	(Note 1a)	-6	A
	– Pulsed		-30	
P _D	Power Dissipation for Single Operation	(Note 1a)	3	W
		(Note 1b)	1.3	
		(Note 1c)	1.1	
T _J , T _{stg}	Operating and Storage Junction Temperature Range		-55 to +150	°C

Thermal Characteristics

R _{eJA}	Thermal Resistance, Junction-to-Ambient	(Note 1a)	42	°C/W		
R _{θJC}	Thermal Resistance, Junction-to-Case	(Note 1)	12	°C/W		

Package Marking and Ordering Information

-	evice Reel S	Size Tape width	Quantity
434 FD	T434P 13'	' 12mm	2500 units

Electrical Characteristics $T_{A} = 25^{\circ}C$ unless otherwise noted Symbol Min Parameter **Test Conditions** Тур Max Units **Off Characteristics** BV_{DSS} Drain-Source Breakdown Voltage -20 V $V_{GS} = 0 V, I_D = -250 \mu A$ Breakdown Voltage Temperature $I_D = -250 \,\mu\text{A}$, Referenced to 25°C -28 mV/°C ΔBV_{DSS} $\Delta T_{\rm J}$ Coefficient $V_{DS} = -16 V, V_{GS} = 0 V$ IDSS Zero Gate Voltage Drain Current -1 μA $V_{DS} = 0 V$ Gate-Body Leakage Current, V_{GS} = 8 V, 100 IGSSF nA Forward Gate-Body Leakage Current, $V_{GS} = -8 V$ $V_{DS} = 0 V$ -100 IGSSR nA Reverse **On Characteristics** (Note 2) Gate Threshold Voltage $V_{GS(th)}$ $V_{DS} = V_{GS}, I_D = -250 \overline{\mu A}$ -0.4 -0.6 -1 V Gate Threshold Voltage $I_D = -250 \ \mu A$, Referenced to $25^{\circ}C$ 2 mV/°C $\Delta V_{GS(th)}$ Temperature Coefficient ΔT_{J} Static Drain-Source $V_{GS} = -4.5 V_{,}$ $I_{D} = -6 A$ 0.040 0.050 R_{DS(on)} Ω $V_{GS} = -2.5 V$, $I_{D} = -4 A$ **On-Resistance** 0.050 0.070 V_{GS} = -4.5 V, I_D = -6 A T_J=125°C 0.067 0.083 V_{DS} = -5 V **On–State Drain Current** V_{GS} = -4.5 V, -20 А I_{D(on)} Forward Transconductance $V_{DS} = -10 V$, $I_{D} = -6 A$ 6.5 S **g**_{FS} **Dynamic Characteristics** $V_{GS} = 0 V$, Ciss Input Capacitance $V_{DS} = -10 V$, 1187 pF f = 1.0 MHz Coss **Output Capacitance** 270 pF **Reverse Transfer Capacitance** pF Crss 114 Switching Characteristics (Note 2) I_D = −1 A, Turn-On Delay Time $V_{DD} = -5 V$, 8 16 t_{d(on)} ns V_{GS} = -4.5 V, $R_{GEN} = 6 \Omega$ tr Turn–On Rise Time 15 25 ns t_{d(off)} Turn–Off Delay Time 45 65 ns tf Turn-Off Fall Time 30 50 ns Q_g Total Gate Charge $V_{DS} = -10 V$, $I_{\rm D} = -6 \, {\rm A},$ 13 19 nC $V_{GS} = -4.5 V$ Qas Gate-Source Charge nC 1.8 Q_{gd} Gate-Drain Charge 3 nC **Drain–Source Diode Characteristics and Maximum Ratings** Maximum Continuous Drain-Source Diode Forward Current -2.5 А I_S Drain-Source Diode Forward V_{SD} $V_{GS} = 0 V$, $I_S = -2.5 A$ (Note 2) -0.75 -1.2 V Voltage Notes: 1. R_{BLA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. $R_{\theta,IC}$ is guaranteed by design while $R_{\theta CA}$ is determined by the user's board design. a) 42°C/W when b) 95°/W when mounted c) 110°/W when mounted on a mounted on a 1in² on a .0066 in² pad of minimum pad. pad of 2 oz copper 2 oz copper

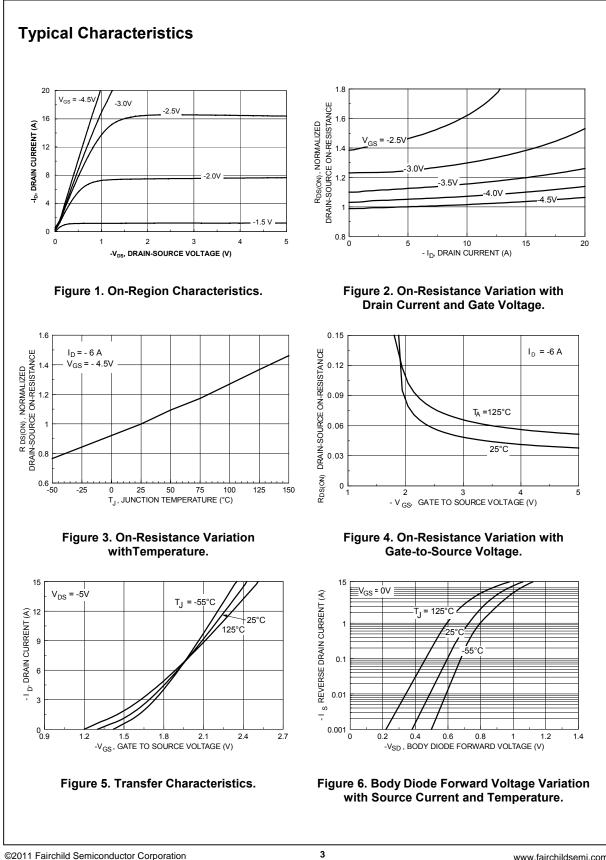
FDT434F

Scale 1 : 1 on letter size paper

2. Pulse Test: Pulse Width < 300µs, Duty Cycle < 2.0%

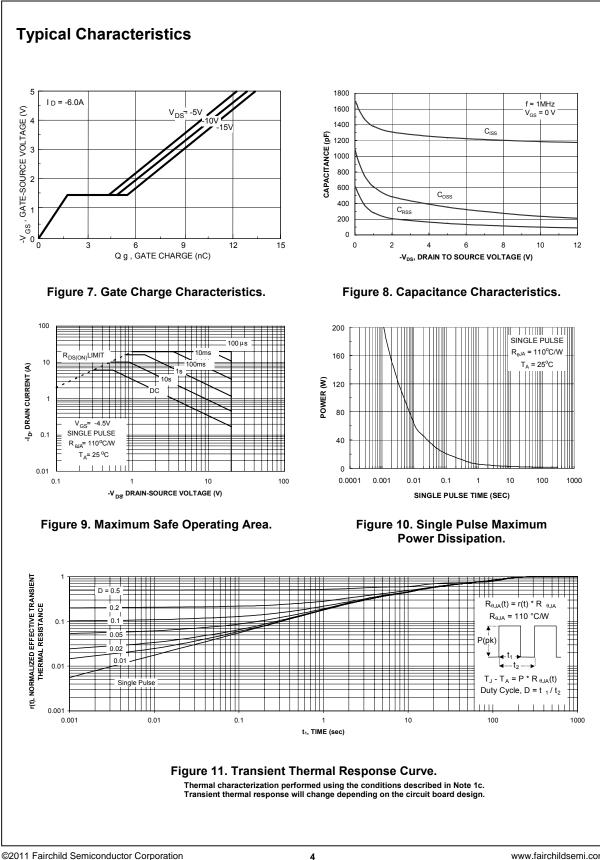
©2011 Fairchild Semiconductor Corporation FDT434P Rev. C2

www.fairchildsemi.com



FDT434P Rev. C2

FDT434P



FDT434P Rev. C2

www.fairchildsemi.com

FDT434P



TRADEMARKS

The following includes registered and unregistered trademarks and service marks, owned by Fairchild Semiconductor and/or its global subsidiaries, and is not intended to be an exhaustive list of all such trademarks.

AccuPower™ Auto-SPM™ АХ-САР™* Build it Now™ CorePLUS™ CorePOWER™ CROSSVOLT™ CTI ™ Current Transfer Logic™ DEUXPEED® Dual Cool™ EcoSPARK[®] EfficentMax™ ESBC™ F® Fairchild®

Fairchild Semiconductor®

FACT Quiet Series™ FACT[®]

Green FPS™ e-Series™ Gmax™ GTO™ IntelliMAX™ ISOPLANAR™ MegaBuck™ MIČROCOUPLER™ MicroFET™ MicroPak™ MicroPak2™ MillerDrive™ MotionMax™ Motion-SPM™ mWSaver™ OptiHiT™ **OPTOLOGIC[®] OPTOPLANAR[®]** R

PDP SPMTM

F-PFS™

FRFET®

Green FPS™

Global Power ResourceSM

Power-SPM™ PowerTrench[®] PowerXS™ Programmable Active Droop™ OFFT QS™ Quiet Series™ RapidConfigure[™] Saving our world, 1mW/W/kW at a time™ SignalWise™ SmartMax™ SMART START™ SPM[®] STEALTH™ SuperFET® SuperSOT™-3 . SuperSOT™-6 SuperSOT™-8 SupreMOS® SyncFET™ Sync-Lock™ SYSTEM ®*

The Right Technology for Your Success™ p wer franchise TinyBoost™ TinyBuck™ TinyCalc™ TinyLogic® TINYOPTO™ TinyPower™ TinyPWM™ TinyWire™ TriFault Detect™ TRUECURRENT®* սSerDes™ UHC® Ultra FRFET™

The Power Franchise[®]

UniFET™ VCX™ VisualMax™ XS™

*Trademarks of System General Corporation, used under license by Fairchild Semiconductor.

DISCLAIMER

FAST®

FPS™

FastvCore™

FETBench™

FlashWriter[®] *

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION, OR DESIGN. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS. THESE SPECIFICATIONS DO NOT EXPAND THE TERMS OF FAIRCHILD'S WORLDWIDE TERMS AND CONDITIONS, SPECIFICALLY THE WARRANTY THEREIN, WHICH COVERS THESE PRODUCTS.

GENERAL

LIFE SUPPORT POLICY FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF FAIRCHILD SEMICONDUCTOR CORPORATION.

As used here in:

- Life support devices or systems are devices or systems which, (a) are 1. intended for surgical implant into the body or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury of the user.
- A critical component in any component of a life support, device, or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness

ANTI-COUNTERFEITING POLICY

Fairchild Semiconductor Corporation's Anti-Counterfeiting Policy. Fairchild's Anti-Counterfeiting Policy is also stated on our external website, www.Fairchildsemi.com, under Sales Support. Counterfeiting of semiconductor parts is a growing problem in the industry. All manufactures of semiconductor products are experiencing counterfeiting of their

parts. Customers who inadvertently purchase counterfeit parts experience many problems such as loss of brand reputation, substandard performance, failed application, and increased cost of production and manufacturing delays. Fairchild is taking strong measures to protect ourselves and our customers from the proliferation of counterfeit parts. Fairchild strongly encourages customers to purchase Fairchild parts either directly from Fairchild or from Authorized Fairchild Distributors who are listed by country on our web page cited above. Products customers buy either from Fairchild directly or from Authorized Fairchild Distributors are genuine parts, have full traceability, meet Fairchild's quality standards for handing and storage and provide access to Fairchild's full range of up-to-date technical and product information. Fairchild and our Authorized Distributors will stand behind all warranties and will appropriately address and warranty issues that may arise. Fairchild will not provide any warranty coverage or other assistance for parts bought from Unauthorized Sources. Fairchild is committed to combat this global problem and encourage our customers to do their part in stopping this practice by buying direct or from authorized distributors.

PRODUCT STATUS DEFINITIONS = 0.5 Definition of Terms

Datasheet Identification	Product Status	Definition	
Advance Information	Formative / In Design	Datasheet contains the design specifications for product development. Specifications may change in any manner without notice.	
Preliminary	First Production	Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.	
No Identification Needed	Full Production	Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.	
Obsolete	Not In Production	Datasheet contains specifications on a product that is discontinued by Fairchild Semiconductor. The datasheet is for reference information only.	